

**BC547 BC547A BC547B BC547C** 



# **NPN General Purpose Amplifier**

This device is designed for use as general purpose amplifiers and switches requiring collector currents to 300 mA. Sourced from Process 10. See PN100A for characteristics.

# **Absolute Maximum Ratings\***

TA = 25°C unless otherwise noted

| Symbol                            | Parameter  | Value       | Units |
|-----------------------------------|--|-------------|-------|
| $V_{CEO}$                         | Collector-Emitter Voltage                        | 45          | V     |
| V <sub>CES</sub>                  | Collector-Base Voltage                           | 50          | V     |
| V <sub>EBO</sub>                  | Emitter-Base Voltage                             | 6.0         | V     |
| I <sub>C</sub>                    | Collector Current - Continuous                   | 500         | mA    |
| T <sub>J</sub> , T <sub>stg</sub> | Operating and Storage Junction Temperature Range | -55 to +150 | °C    |

<sup>\*</sup>These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

- These ratings are based on a maximum junction temperature of 150 degrees C.
   These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.

## **Thermal Characteristics**

TA = 25°C unless otherwise noted

| Symbol          | Characteristic                          | Max               | Units |
|-----------------|---|-------------------|-------|
|                 |   | BC547 / A / B / C |       |
| $P_D$           | Total Device Dissipation                | 625               | mW    |
|                 | Derate above 25°C                       | 5.0               | mW/°C |
| $R_{\theta JC}$ | Thermal Resistance, Junction to Case    | 83.3              | °C/W  |
| $R_{\theta JA}$ | Thermal Resistance, Junction to Ambient | 200               | °C/W  |

# NPN General Purpose Amplifier (continued)

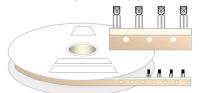
| Symbol               | Parameter                                       | Test Conditions   | Min               | Max               | Units    |
|----------------------|---|---|-------------------|-------------------|----------|
| OFF CHA              | RACTERISTICS                                    |   |                   |                   |          |
| $V_{(BR)CEO}$        | Collector-Emitter Breakdown Voltage             | $I_C = 1.0 \text{ mA}, I_B = 0$   | 45                |                   | V        |
| V <sub>(BR)CBO</sub> | Collector-Base Breakdown Voltage                | $I_C = 10 \mu A, I_E = 0$   | 50                |                   | V        |
| V <sub>(BR)CES</sub> | Collector-Base Breakdown Voltage                | $I_C = 10 \mu A, I_E = 0$   | 50                |                   | V        |
| V <sub>(BR)EBO</sub> | Emitter-Base Breakdown Voltage                  | $I_E = 10  \mu A, I_C = 0$  | 6.0               |                   | V        |
| I <sub>CBO</sub>     | Collector Cutoff Current                        | $V_{CB} = 30 \text{ V}, I_E = 0$<br>$V_{CB} = 30 \text{ V}, I_E = 0, T_A = +150 ^{\circ}\text{C}$ |                   | 15<br>5.0         | nA<br>μA |
| h <sub>FE</sub>      | DC Current Gain                                 | $V_{CE} = 5.0 \text{ V}, I_C = 2.0 \text{ mA}$ 547 547A 547B                                      | 110<br>110<br>200 | 800<br>220<br>450 |          |
|                      |   | 547C  | 420               | 800               |          |
| $V_{\text{CE(sat)}}$ | Collector-Emitter Saturation Voltage            | $I_C = 10 \text{ mA}, I_B = 0.5 \text{ mA}$<br>$I_C = 100 \text{ mA}, I_B = 5.0 \text{ mA}$       |                   | 0.25<br>0.60      | V        |
| V <sub>BE(on)</sub>  | Base-Emitter On Voltage                         | $V_{CE} = 5.0 \text{ V}, I_{C} = 2.0 \text{ mA}$ $V_{CE} = 5.0 \text{ V}, I_{C} = 10 \text{ mA}$  | 0.58              | 0.70<br>0.77      | V        |
| SMALL S              | IGNAL CHARACTERISTICS Small-Signal Current Gain | $I_{C} = 2.0 \text{ mA}, V_{CE} = 5.0 \text{ V},$   | 125               | 900               |          |
|                      |   | f = 1.0 kHz   |                   |                   |          |
| NF                   | Noise Figure                                    | $V_{CE} = 5.0 \text{ V}, I_{C} = 200 \mu\text{A},$  |                   | 10                | dB       |

### **TO-92 Tape and Reel Data** FAIRCHILD SEMICONDUCTOR TM **TO-92 Packaging** Configuration: Figure 1.0 **TAPE and REEL OPTION** FSCINT Label sample See Fig 2.0 for various Reeling Styles CBVK//418019 **FSCINT** Label 5 Reels per Intermediate Box Customized F63TNR Label sample Label F63TNR LOT: CBVK741B019 QTY: 2000 FSID: PN222N Customized QTY1: QTY2: Label 375mm x 267mm x 375mm Intermediate Box TO-92 TNR/AMMO PACKING INFROMATION **AMMO PACK OPTION** See Fig 3.0 for 2 Ammo Packing Style Quantity EOL code **Pack Options** 2,000 D26Z Е 2,000 D27Z Ammo М 2,000 D74Z D75Z 2,000 **FSCINT** Unit weight = 0.22 gm Reel weight with components = 1.04 kg Ammo weight with components = 1.02 kg Max quantity per intermediate box = 10,000 units Label 5 Ammo boxes per Intermediate Box 327mm x 158mm x 135mm Immediate Box Customized F63TNR Customized Label Label 333mm x 231mm x 183mm Intermediate Box (TO-92) BULK PACKING INFORMATION **BULK OPTION** See Bulk Packing DESCRIPTION QUANTITY Information table J18Z TO-18 OPTION STD 2.0 K / BOX Anti-static Bubble Sheets TO-5 OPTION STD NO LEAD CLIP 1.5 K / BOX J05Z **FSCINT Label** NO EOL TO-92 STANDARD STRAIGHT FOR: PKG 92, NO LEADCLIP 2.0 K / BOX 94 (NON PROELECTRON SERIES), 96 TO-92 STANDARD STRAIGHT FOR: PKG 94 (PROELECTRON SERIES BCXXX, BFXXX, BSRXXX), 97, 98 L34Z NO LEADCLIP 2.0 K / BOX 2000 units per 114mm x 102mm x 51mm EO70 box for std option Immediate Box 5 EO70 boxes per intermediate Box 530mm x 130mm x 83mm Customized Intermediate box Label FSCINT Label 10,000 units maximum per intermediate box for std option

# TO-92 Tape and Reel Data, continued

# **TO-92 Reeling Style Configuration:** Figure 2.0

## Machine Option "A" (H)

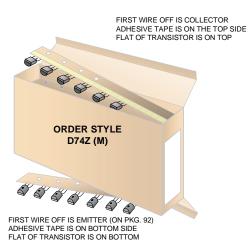


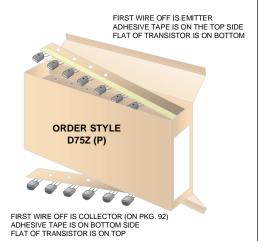
Style "A", D26Z, D70Z (s/h)

# Machine Option "E" (J)

Style "E", D27Z, D71Z (s/h)

# **TO-92 Radial Ammo Packaging Configuration:** Figure 3.0



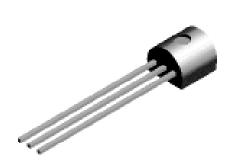


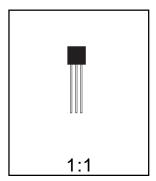


# **TO-92 Package Dimensions**



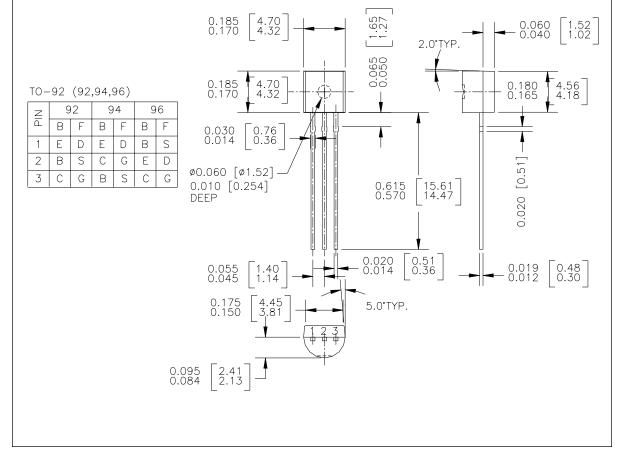
# TO-92 (FS PKG Code 92, 94, 96)





Scale 1:1 on letter size paper
Dimensions shown below are in:
inches [millimeters]

Part Weight per unit (gram): 0.1977



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|--------------------------|---------------------------|---|
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